

Vishay Semiconductors

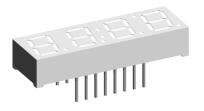
Clock Display

Description

Four digit Display, with 10 mm digit charactersize. Designed as clock Display with active colon between digit two and three.

Features

- High efficient AllnGAP technology
- Dark surface, white segments
- Common anode (TDC.1050m)
- Common cathode (TDC.1060m)
- · Recommended viewing distance up to 7 meter
- · Multiplex mode
- · Lead-free device





Applications

Clock modules for Video/Audioequipment, Instrumentation, Set Top Boxes

Parts Table

Part	Color, Luminous Intensity	Circuitry
TDCG1050m	Green, I _V = (2.8 to 4.0) mcd	Common anode
TDCG1060m	Green, I _V = (2.8 to 4.0) mcd	Common cathode
TDCR1050m	Red, I _V = (4.0 to 6.0) mcd	Common anode
TDCR1060m	Red, I _V = (4.0 to 6.0) mcd	Common cathode
TDCY1050m	Super Yellow, I _V = (4.0 to 8.0) mcd	Common anode
TDCY1060m	Super Yellow, I _V = (4.0 to 8.0) mcd	Common cathode

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

TDCG1050m/ TDCG1060m, TDCR1050m/ TDCR1060m, TDCY1050m/ TDCY1060m,

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V _R	5	V
Forward current		I _F	25	mA
Operating temperature range		T _{amb}	- 40 to + 85	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Soldering temperature		T _{sd}	260 ± 5	°C
Power dissipation		P _V	60	mW
Peak forward current	(Duty 1/10 @ 1kHz)	I _F (Peak)	160	mA

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Optical and Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Red

TDCR1050m/TDCR1060m

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Luminous intensity per	I _F = 2 mA	TDCR1050m	I _V		1.5		mcd
segment 1)							
		TDCR1060m	I _V		1.5		mcd
	I _F = 10 mA	TDCR1050m	I _V	4.0	6.0		mcd
		TDCR1060m	I _V	4.0	6.0		mcd
Luminous intensity of colon	I _F = 2 mA	TDCR1050m	I _V		0.4		mcd
		TDCR1060m	I _V		0.4		mcd
	I _F = 10 mA	TDCR1050m	I _V	0.5	0.8		mcd
		TDCR1060m	I _V	0.5	0.8		mcd
Dominant wavelength	I _F = 20 mA		λ_{d}		631		nm
Peak wavelength	I _F = 20 mA		λ_{p}		639		nm
Spectral bandwidth	I _F = 20 mA		Δλ		20		nm
Forward voltage	I _F = 20 mA		V_{F}		2.0	2.4	V
Reverse current	V _R = 5 V		I _R			10	μΑ

Note¹⁾ I_{Vmin} and I_{V} groups are mean values of all segments (a to g, D1 to D4), matching factor within segments is \geq 0.5, excluding decimal points and colon.

Yellow

TDCY1050m/TDCY1060m

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Luminous intensity per	I _F = 2 mA	TDCY1050m	I _V		1.5		mcd
segment 1)							
		TDCY1060m	I _V		1.5		mcd
	I _F = 10 mA	TDCY1050m	I _V	4.0	8.0		mcd
		TDCY1060m	I _V	4.0	8.0		mcd
Luminous intensity of colon	I _F = 2 mA	TDCY1050m	I _V		0.4		mcd
		TDCY1060m	I _V		0.4		mcd
	I _F = 10 mA	TDCY1050m	I _V	0.5	1.0		mcd
		TDCY1060m	I _V	0.5	1.0		mcd
Dominant wavelength	I _F = 20 mA		λ_{d}		589		nm
Peak wavelength	I _F = 20 mA		λ_{p}		591		nm
Spectral bandwidth	I _F = 20 mA		Δλ		15		nm
Forward voltage	I _F = 20 mA		V _F		2.0	2.4	V
Reverse current	V _R = 5 V		I _R			10	μΑ

Note¹⁾ I_{Vmin} and I_{V} groups are mean values of all segments (a to g, D1 to D4), matching factor within segments is \geq 0.5, excluding decimal points and colon.





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Green

TDCG1050m/ TDCG1060m

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Luminous intensity per	I _F = 2 mA	TDCG1050m	I _V		1.0		mcd
segment 1)							
		TDCG1060m	I _V		1.0		mcd
	I _F = 10 mA	TDCG1050m	I _V	2.8	4.0		mcd
		TDCG1060m	I _V	2.8	4.0		mcd
Luminous intensity of colon	I _F = 2 mA	TDCG1050m	I _V		0.2		mcd
		TDCG1060m	I _V		0.2		mcd
	I _F = 10 mA	TDCG1050m	I _V	0.5	1.2		mcd
		TDCG1060m	I _V	0.5	1.2		mcd
Dominant wavelength	I _F = 20 mA		λ_{d}	562	573	575	nm
Peak wavelength	I _F = 20 mA		λ_{p}		575		nm
Spectral bandwidth	I _F = 20 mA		Δλ		20		nm
Forward voltage	I _F = 20 mA		V_{F}		2.0	2.4	V
Reverse current	V _R = 5 V		I _R			10	μΑ

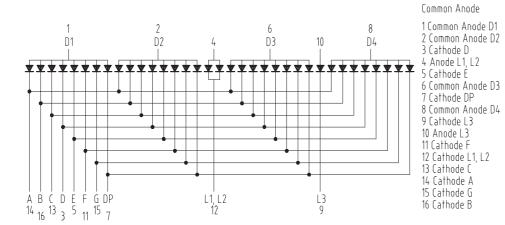
Note¹⁾ I_{Vmin} and I_{V} groups are mean values of all segments (a to g, D1 to D4), matching factor within segments is \geq 0.5, excluding decimal points and colon.

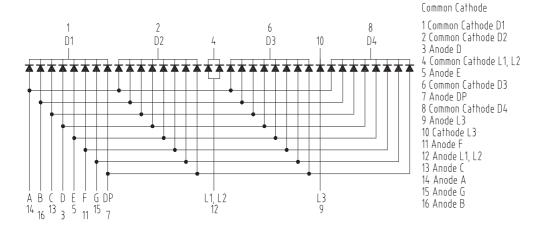
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Pinning







Drawing-No.: 6.544-5332.01-4 Bl. 2

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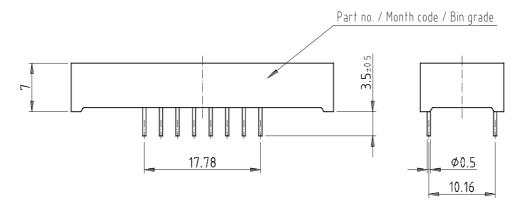
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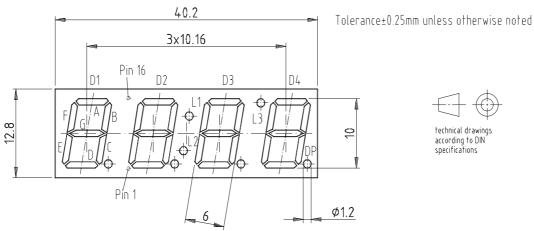
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Package Dimensions in mm





Drawing-No.: 6.544-5332.01-4 Bl. 1

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TDCG / R / Y10..m

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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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